



2DB1386Q/R

### 20V PNP MEDIUM POWER TRANSISTOR IN SOT89

### **Features**

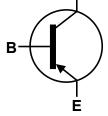
- BV<sub>CEO</sub> > -20V
- I<sub>C</sub> = -5A high Continuous Current
- Low saturation voltage V<sub>CE(sat)</sub> < -1V @ -4A</li>
- Complementary NPN Type: 2DD2098
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

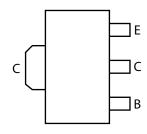
## **Mechanical Data**

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>3</sup>
- Weight: 0.052 grams (approximate)









Top View

Device Symbol

Pin Out – Top View

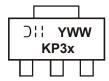
### Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
2DB1386Q-13	KP3Q	13	12	2,500
2DB1386Q-13R	KP3Q	13	12	4,000
2DB1386R-13	KP3R	13	12	2,500

#### Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

## **Marking Information**



KP3x = Product Type Marking Code, where: KP3Q = 2DB1386Q

KP3R = 2DB1386R

YWW = Date Code Marking Y = Last digit of year (ex: 7 = 2007) WW = Week code (01 - 53)



### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-30	V
Collector-Emitter Voltage	$V_{CEO}$	-20	V
Emitter-Base Voltage	$V_{EBO}$	-6	V
Continuous Collector Current	Ic	-5	Α
Peak Pulse Current	I <sub>CM</sub>	-10	Α
Base Current	Ι <sub>Β</sub>	-500	mA

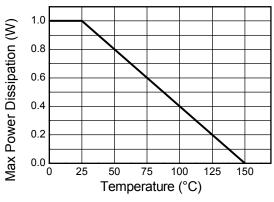
## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

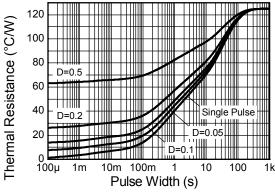
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	1	W
Thermal Resistance, Junction to Ambient Air (Note 5)	$R_{ hetaJA}$	125	°C/W
Thermal Resistance, Junction to Leads (Note 6)	$R_{ heta JL}$	19	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes:

- 5. For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in steady state condition.
- 6. Thermal resistance from junction to solder-point (on the exposed collector pad).

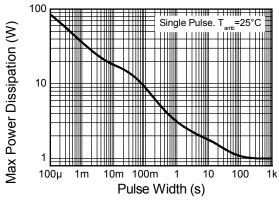
### **Thermal Characteristics and Derating Information**





### **Derating Curve**

**Transient Thermal Impedance** 



**Pulse Power Dissipation** 

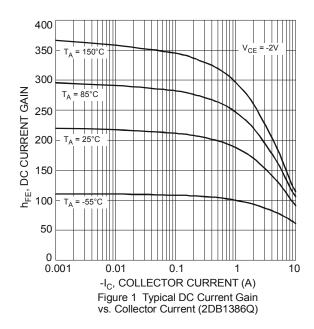


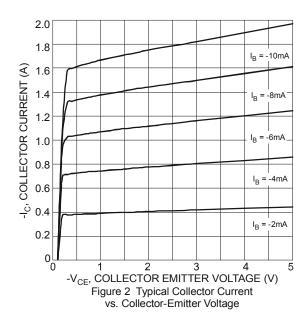
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Conditions
OFF CHARACTERISTICS (N	OFF CHARACTERISTICS (Note 7)						
Collector-Base Breakdown Voltage		BV <sub>CBO</sub>	-30	_	_	V	$I_C = -50\mu A$ , $I_E = 0$
Collector-Emitter Breakdown Voltage			-20			V	$I_{C} = -1 \text{mA}, I_{B} = 0$
Emitter-Base Breakdown Voltage		BV <sub>EBO</sub>	-6	_		V	$I_E = -50\mu A, I_C = 0$
Collector Cut-Off Current		I <sub>CBO</sub>	_	_	-0.5	μΑ	$V_{CB} = -20V, I_{E} = 0$
Emitter Cut-Off Current		I <sub>EBO</sub>	_	_	-0.5	μΑ	$V_{EB} = -5V, I_{C} = 0$
ON CHARACTERISTICS (No	ON CHARACTERISTICS (Note 7)						
Collector-Emitter Saturation Voltage		V <sub>CE(SAT)</sub>	_	-0.25	-1.0	V	$I_C = -4A$ , $I_B = -0.1A$
DC Current Gain	2DB1386Q		120	_	270		$I_C = -0.5A$ , $V_{CF} = -2V$
DC Current Gain	2DB1386R		180	_	390	_	IC = -0.5A, VCE = -2V
SMALL SIGNAL CHARACTERISTICS							
Output Capacitance		$C_{obo}$	_	55	_	pF	$V_{CB} = -20V$ , $I_E = 0$ , $f = 1MHz$
Current Gain-Bandwidth Product		f⊤	_	100	_	MHz	$V_{CE}$ = -6V, $I_E$ = 50mA, $f$ = 30MHz

Notes: 7. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

# Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)







## Typical Electrical Characteristics (cont.)

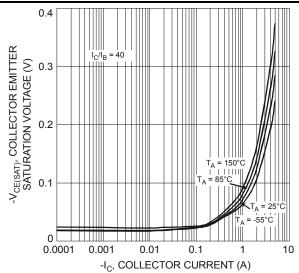


Figure 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

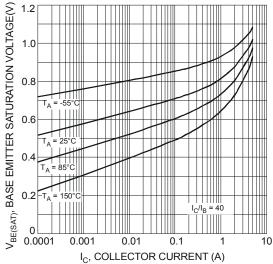


Figure 5 Typical Base-Emitter Saturation Voltage vs. Collector Current

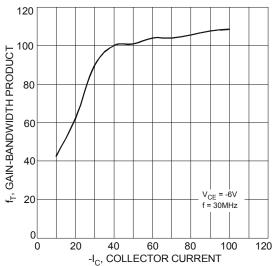


Figure 7 Typical Gain-Bandwidth Product vs. Collector Current

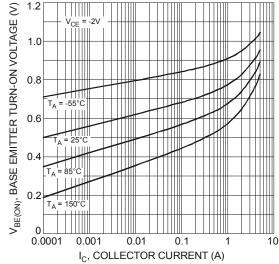


Figure 4 Typical Base-Emitter Turn-On Voltage vs. Collector Current

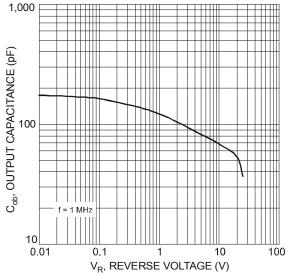
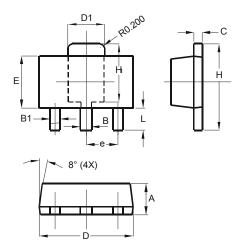


Figure 6 Typical Output Capacitance Characteristics



# **Package Outline Dimensions**

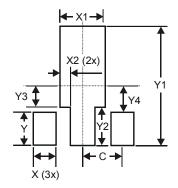
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.44		
<b>D</b> 4.40		4.60		
D1	1.62	1.83		
Е	2.29	2.60		
е	1.50 Typ			
Н	3.94	4.25		
H1	2.63	2.93		
L	0.89	1.20		
All Dimensions in mm				

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Υ	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1 500



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